Rochester Electronics

Datasheet

PART NUMBER

DM54173JB-ROCV

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All re-creations are done with the approval of the Original Component Manufacturer. (OCM)

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
    - Class Q Military
    - Class V Space Level

Qualified Suppliers List of Distributors (QSLD)

- Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OCM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

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National Semiconductor

June 1989

54173/DM54173/DM74173 TRI-STATE® Quad D Registers

General Description

These four-bit registers contain D-type flip-flops with totem-pole TRI-STATE outputs, capable of driving highly capacitive or low-impedance loads. The high-impedance state and increased high-logic-level drive provide these flip-flops with the capability of driving the bus lines in a bus-organized system without need for interface or pull-up components.

Gated enable inputs are provided for controlling the entry of data into the flip-flops. When both data-enable inputs are low, data at the D inputs are loaded into their respective flip-flops on the next positive transition of the buffered clock input. Gate output control inputs are also provided. When both are low, the normal logic states of the four outputs are available for driving the loads or bus lines. The outputs are disabled independently from the level of the clock by a high logic level at either output control input. The outputs then present a high impedance and neither load nor drive the bus line. Detailed operation is given in the function table.

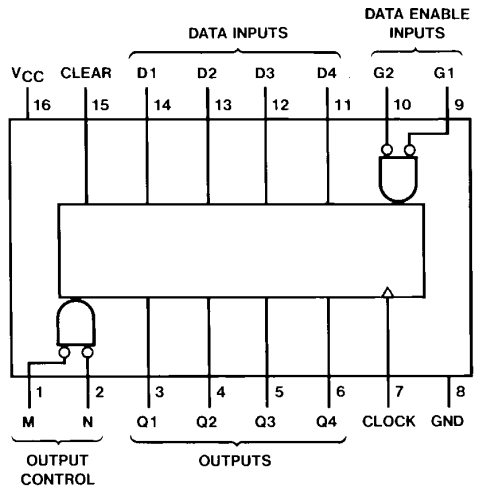
To minimize the possibility that two outputs will attempt to take a common bus to opposite logic levels, the output control circuitry is designed so that the average output disable times are shorter than the average output enable times.

Features

- TRI-STATE outputs interface directly with system bus
- Gated output control lines for enabling or disabling the outputs
- Fully independent clock elminates restrictions for operating in one of two modes:
  - Parallel load
  - Do nothing (hold)
- For application as bus buffer registers
- Typical propagation delay 18 ns
- Typical frequency 30 MHz
- Typical power dissipation 250 mW
- Alternate Military/Aerospace device (54173) is available. Contact a National Semiconductor Sales Office/ Distributor for specifications.

Connection Diagram

Dual-In-Line Package



TL/F/6556–1

Order Number 54173DMQB, 54173FMQB, DM54173J, DM54173W or DM74173N
See NS Package Number J16A, N16E or W16A

Function Table

Inputs					Output Q
Clear	Clock	Data Enable G1	Data Enable G2	Data D	
H	X	X	X	X	L
L	L	X	X	X	Q_0
L	↑	H	X	X	Q_0
L	↑	X	H	X	Q_0
L	↑	L	L	L	L
L	↑	L	L	H	H

When either M or N (or both) is (are) high the output is disabled to the high-impedance state; however, sequential operation of the flip-flops is not affected.

H = high level (steady state)

L = low level (steady state)

↑ = low-to-high level transition

X = don't care (any input including transitions)

Q_0 = the level of Q before the indicated steady state input conditions were established

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

 TL/F/6556 RRD-B30M105/Printed in U. S. A.

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	7V
Input Voltage	5.5V
Operating Free Air Temperature Range	
DM54 and 54	−55°C to +125°C
DM74	0°C to +70°C
Storage Temperature Range	−65°C to +150°C

Note: *The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.*

Recommended Operating Conditions

Symbol	Parameter		DM54173			DM74173			Units
			Min	Nom	Max	Min	Nom	Max	
V_{CC}	Supply Voltage		4.5	5	5.5	4.75	5	5.25	V
V_{IH}	High Level Input Voltage		2			2			V
V_{IL}	Low Level Input Voltage				0.8			0.8	V
I_{OH}	High Level Output Current				−2			−5.2	mA
I_{OL}	Low Level Output Current				16			16	mA
f_{CLK}	Clock Frequency (Note 4)		0		25	0		25	MHz
t_W	Pulse Width (Note 4)	Clock	20			20			ns
		Clear	20			20			
t_{SU}	Setup Time (Note 4)	Enable	17			17			ns
		Data	10			10			
t_H	Hold Time (Note 4)	Enable	2			2			ns
		Data	10			10			
t_{REL}	Clear Release Time (Note 4)		10			10			ns
T_A	Free Air Operating Temperature		−55		125	0		70	°C

Electrical Characteristics over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions		Min	Typ (Note 1)	Max	Units
V_I	Input Clamp Voltage	V_{CC} = Min, I_I = −12 mA				−1.5	V
V_{OH}	High Level Output Voltage	V_{CC} = Min, I_{OH} = Max V_{IL} = Max, V_{IH} = Min		2.4			V
V_{OL}	Low Level Output Voltage	V_{CC} = Min, I_{OL} = Max V_{IH} = Min, V_{IL} = Max				0.4	V
I_I	Input Current @ Max Input Voltage	V_{CC} = Max, V_I = 5.5V				1	mA
I_{IH}	High Level Input Current	V_{CC} = Max, V_I = 2.4V				40	μA
I_{IL}	Low Level Input Current	V_{CC} = Max, V_I = 0.4V				−1.6	mA
I_{OZH}	Off-State Output Current with High Level Output Voltage Applied	V_{CC} = Max, V_O = 2.4V V_{IH} = Min, V_{IL} = Max				40	μA
I_{OZL}	Off-State Output Current with Low Level Output Voltage Applied	V_{CC} = Max, V_O = 0.4V V_{IH} = Min, V_{IL} = Max				−40	μA
I_{OS}	Short Circuit Output Current	V_{CC} = Max (Note 2)	DM54	−30		−70	mA
			DM74	−30		−70	
I_{CC}	Supply Current	V_{CC} = Max (Note 3)			50	72	mA

Note 1: All typicals are at V_{CC} = 5V, T_A = 25°C.

Note 2: Not more than one output should be shorted at a time.

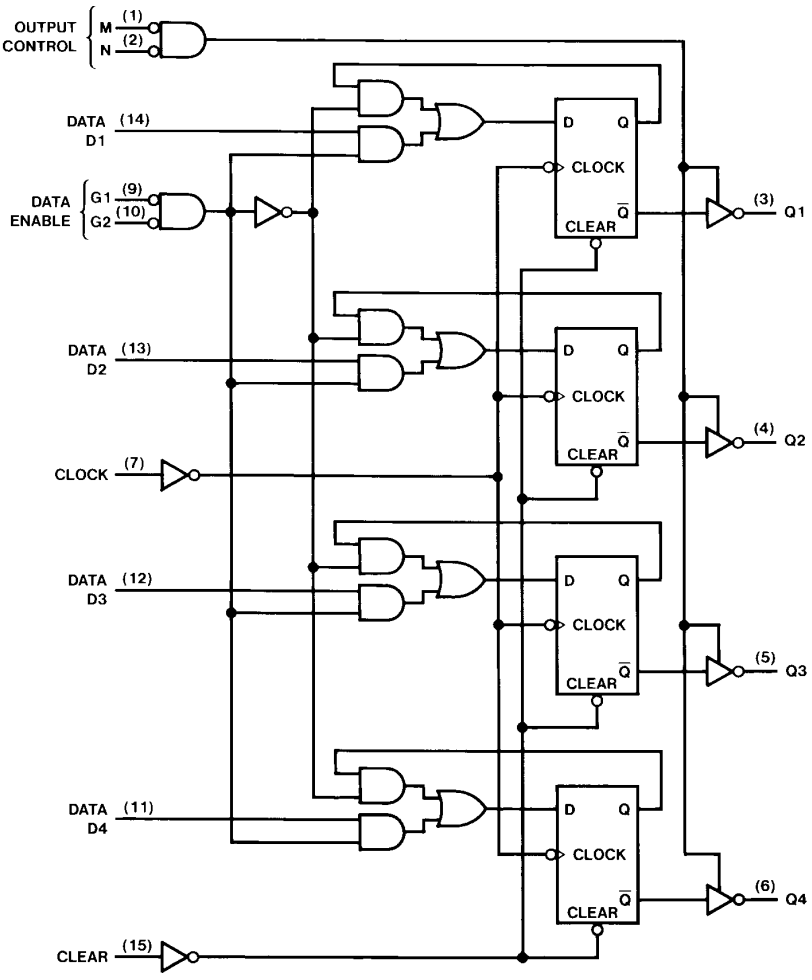
Note 3: I_{CC} is measured with all outputs open, CLEAR grounded after a momentary connection to 4.5V: N, G1, G2 and all DATA inputs grounded: and the CLOCK input and M input at 4.5V.

Note 4: T_A = 25°C and V_{CC} = 5V.

Switching Characteristics at V_{CC} = 5V and T_A = 25°C (See Section 1 for Test Waveforms and Output Load)

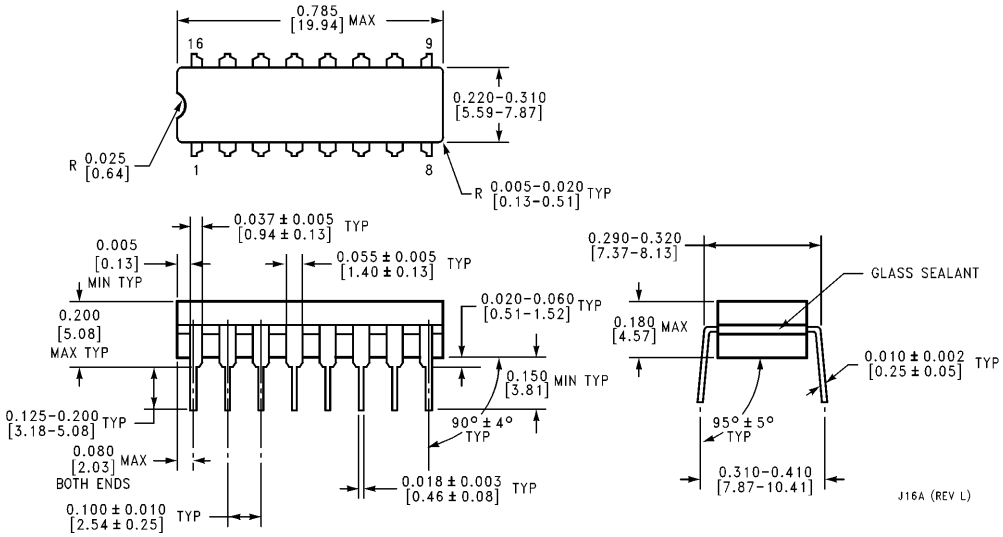
Symbol	Parameter	From (Input) To (Output)	R_L = 400Ω				Units
			C_L = 5 pF		C_L = 50 pF		
			Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency				25		MHz
t_{PLH}	Propagation Delay Time Low to High Level Output	Clock to Output				25	ns
t_{PHL}	Propagation Delay Time High to Low Level Output	Clock to Output				28	ns
t_{PHL}	Propagation Delay Time High to Low Level Output	Clear to Output				27	ns
t_{PZH}	Output Enable Time to High Level Output	Output Control to Q			7	30	ns
t_{PZL}	Output Enable Time to Low Level Output	Output Control to Q			7	30	ns
t_{PHZ}	Output Disable Time from High Level Output	Output Control to Q	3	14			ns
t_{PLZ}	Output Disable Time from Low Level Output	Output Control to Q	3	20			ns

Logic Diagram

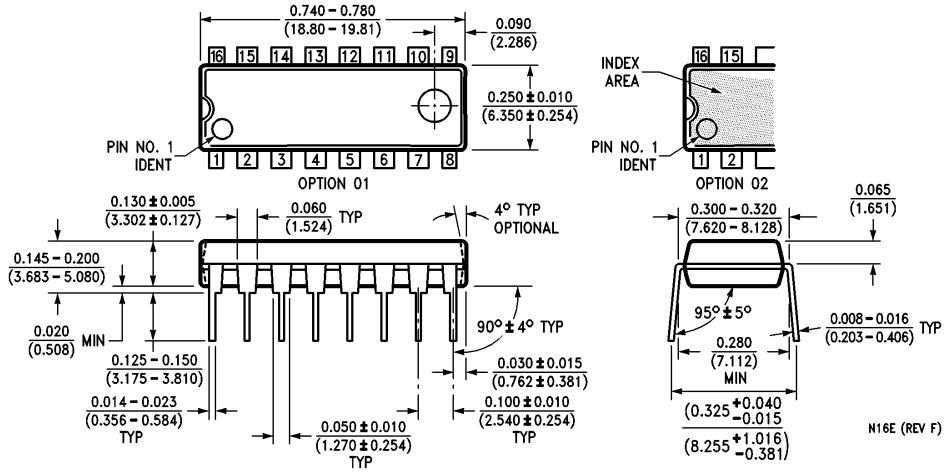


TL/F/6556–2

Physical Dimensions inches (millimeters)

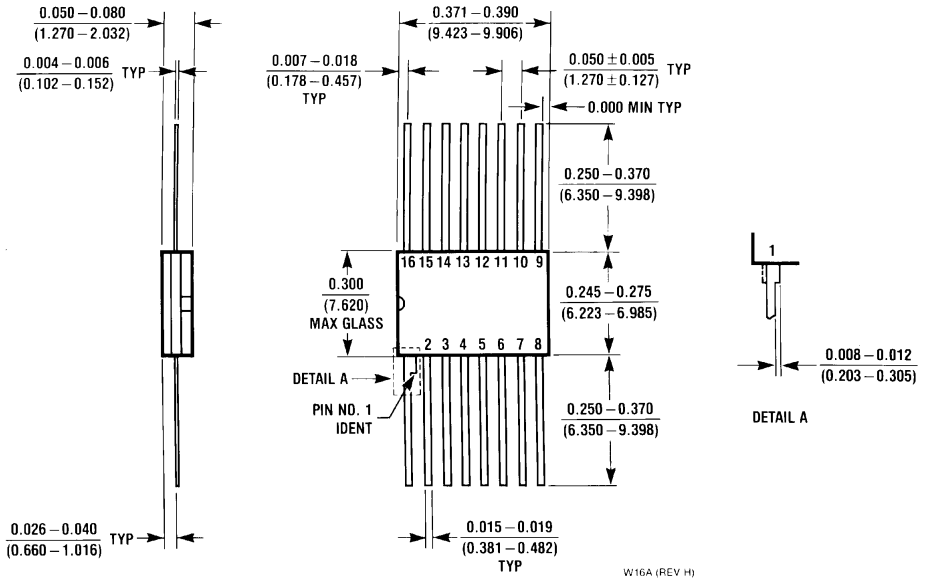


16-Lead Ceramic Dual-In-Line Package (J)
Order Number 54173DMQB or DM54173J
NS Package Number J16A



16-Lead Molded Dual-In-Line Package (N)
Order Number DM74173N
NS Package Number N16E

Physical Dimensions inches (millimeters) (Continued)



16-Lead Ceramic Flat Package (W)
Order Number 54173FMQB or DM54173W
NS Package Number W16A

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National Semiconductor Corporation
1111 West Bardin Road
Arlington, TX 76017
Tel: 1(800) 272-9959
Fax: 1(800) 737-7018

National Semiconductor Europe
Fax: (+49) 0-180-530 85 86
Email: cnjwge@tevm2.nsc.com
Deutsch Tel: (+49) 0-180-530 85 85
English Tel: (+49) 0-180-532 78 32
Français Tel: (+49) 0-180-532 93 58
Italiano Tel: (+49) 0-180-534 16 80

National Semiconductor Hong Kong Ltd.
13th Floor, Straight Block,
Ocean Centre, 5 Canton Rd.
Tsimshatsui, Kowloon
Hong Kong
Tel: (852) 2737-1600
Fax: (852) 2736-9960

National Semiconductor Japan Ltd.
Tel: 81-043-299-2309
Fax: 81-043-299-2408